

## CPPP 4 P OPTICAL PROPERTIES OF $\text{Cu}_2\text{ZnGeSe}_4$

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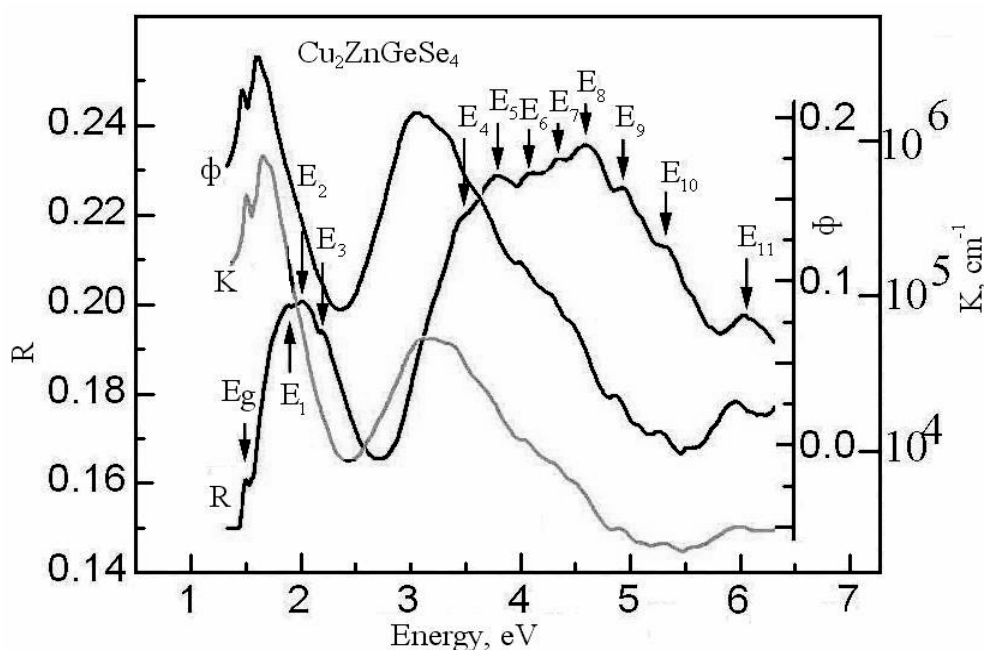
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$\text{Cu}_2\text{ZnGeSe}_4$  (CZGSe) is interesting and promising *p*-type semiconductor materials for optoelectronics applications and solar cells [1]. In this paper we present reflectivity spectra measured at 300 K in the photon energy range of 1.5 - 6 eV. CZGSe crystals were grown by one-temperature method. A temperature of furnace was risen at the speed of ~50 K/h up to 1200 K. Directional crystallization of the melt was carried out by decreasing the temperature of the furnace at the speed of ~2 K/h down to ~1020 K; homogenizing annealing of the obtained ingots was carried out at this temperature for 300 h. The composition of the crystals was determined by the energy dispersive X-ray micro-analysis (EDAX). The average atomic ratio of Cu:Zn:Ge:Se was found to be close to stoichiometry. The reflectivity is measured using two-beam spectrometer Specord M-40.



*Fig.1. Reflectivity spectra ( $R$ ), the extinction coefficient ( $K$ ) and phase of reflected ray ( $\phi$ ) vs energy.*

The  $\text{Cu}_2\text{ZnGeSe}_4$  crystals show well pronounced structures of the reflectivity spectra in the range of  $E \geq E_g$  at 300 K as presented in Fig. 1. Up to 12 peaks are observed. The spectral dependences of the real  $\epsilon_1$  and imaginary  $\epsilon_2$  component of the complex dielectric function  $\epsilon(E) = \epsilon_1(E) + i\epsilon_2(E)$ , the complex refractive index, extinction coefficient and absorption coefficients of CZGSe crystals has been calculated. The energy band structure of  $\text{Cu}_2\text{ZnGeSe}_4$  at photon energies higher than the fundamental band gap is derived from the analysis of the structures observed in  $\epsilon(E)$  spectra.

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[1] H. Matsushita, T. Ochiai, A. Katsui. *J. Cryst. Growth* **275** (2005) e995.